

MOSFET

Small-Signal Transistor

Features

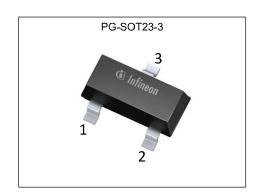
- N-channel
- Depletion mode
- dv/dt rated
- Halogen free according to IEC61249-2-21
 Pb-free lead-plating; RoHS compliant

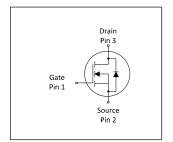
Product validation

Fully qualified according to JEDEC for Industrial Applications

Table 1 **Key Performance Parameters**

rable i regirermanee i arametere								
Parameter	Value	Unit						
$V_{ t DS}$	250	V						
R _{DS(on),max}	30	Ω						
I _{DSS,min}	0.03	A						
ESD Sensitivity, JESD22-A114 (HBM)	Class 0 (<250V)							











Type / Ordering Code	Package	Marking	Related Links
BSS139I	PG-SOT23	Tls	-



Table of Contents

Description	1
Maximum ratings	3
Thermal characteristics	3
Electrical characteristics	3
Electrical characteristics diagrams	5
Package Outlines	9
Revision History	0
Trademarks1	0
Disclaimer	10



1 Maximum ratings at T_A =25 °C, unless otherwise specified

Table 2 **Maximum ratings**

Damanastan	C	Values			11	
Parameter	Symbol	Min.	Тур.	Max.	Unit	Note / Test Condition
Continuous drain current	I _D	-	-	0.10 0.08	А	T _A =25 °C T _A =70 °C
Pulsed drain current	I _{D,pulse}	-	-	0.4	Α	T _A =25 °C
Reverse diode dv/dt	d <i>v</i> /d <i>t</i>	-	-	6	kV/µs	/ _D =0.1 A, V _{DS} =200 V, d <i>i</i> /d <i>t</i> =200 A/μs, / _{T_{j,max}=150 °C}
Gate source voltage	V _{GS}	-20	-	20	V	-
Power dissipation	P _{tot}	-	-	0.36	W	T _A =25 °C
Operating and storage temperature	$T_{\rm j},~T_{\rm stg}$	-55	-	150	°C	IEC climatic category; DIN IEC 68-1: 55/150/56

2 Thermal characteristics

Table 3 Thermal characteristics

Dovometer	Symbol	Values			Linit	Note / Took Condition
Parameter	Symbol	Min.	Тур.	Max.	Unit	Note / Test Condition
Thermal resistance, junction - ambient, minimal footprint	R_{thJA}	-	-	350	K/W	-

Electrical characteristics

at T_j =25 °C, unless otherwise specified

Table 4 **Static characteristics**

D	C		Values			
Parameter	Symbol	Min.	Тур.	Max.	Unit	Note / Test Condition
Drain-source breakdown voltage	V _{(BR)DSS}	250	-	-	V	V _{GS} =-3 V, I _D =250 μA
Gate threshold voltage	$V_{\rm GS(th)}$	-2.1	-1.4	-1	V	V _{DS} =3 V, I _D =56 μA
Drain-source cutoff current	I _{D(off)}	-	-	0.1 10	μA	V _{DS} =250 V, V _{GS} =-3 V, T _j =25 °C V _{DS} =250 V, V _{GS} =-3 V, T _j =125 °C
Gate-source leakage current	I _{GSS}	-	-	10	nA	V _{GS} =20 V, V _{DS} =0 V
On-state drain current	I _{DSS}	30	-	-	mA	V _{GS} =0 V, V _{DS} =10 V
Drain-source on-state resistance	R _{DS(on)}	-	12.5 7.8	30 14	Ω	V _{GS} =0 V, I _D =15 mA V _{GS} =10 V, I _D =0.1 A
Transconductance	g_{fs}	0.060	0.13	-	S	V _{DS} >2 I _D R _{DS(on)max} , I _D =0.08 A



Table 5 Dynamic characteristics

Danamatan	Complete I	Values			11:4	Note / Tool One little
Parameter	Symbol	Min.	Тур.	Max.	Unit	Note / Test Condition
Input capacitance	C _{iss}	-	60	_	pF	V _{GS} =-3 V, V _{DS} =25 V, f=1 MHz
Output capacitance	Coss	-	6.7	_	pF	V _{GS} =-3 V, V _{DS} =25 V, f=1 MHz
Reverse transfer capacitance	C _{rss}	-	2.6	-	pF	V _{GS} =-3 V, V _{DS} =25 V, <i>f</i> =1 MHz
Turn-on delay time	$t_{\sf d(on)}$	-	5.8	-	ns	$V_{\rm DD}$ =125 V, $V_{\rm GS}$ =-3 to 5 V, $I_{\rm D}$ =0.04 A, $R_{\rm G}$ =6 Ω
Rise time	t _r	-	5.4	-	ns	$V_{\rm DD}$ =125 V, $V_{\rm GS}$ =-3 to 5 V, $I_{\rm D}$ =0.04 A, $R_{\rm G}$ =6 Ω
Turn-off delay time	$t_{\sf d(off)}$	-	29	-	ns	$V_{\rm DD}$ =125 V, $V_{\rm GS}$ =-3 to 5 V, $I_{\rm D}$ =0.04 A, $R_{\rm G}$ =6 Ω
Fall time	t _f	-	182	-	ns	$V_{\rm DD}$ =125 V, $V_{\rm GS}$ =-3 to 5 V, $I_{\rm D}$ =0.04 A, $R_{\rm G}$ =6 Ω

Table 6 Gate charge characteristics

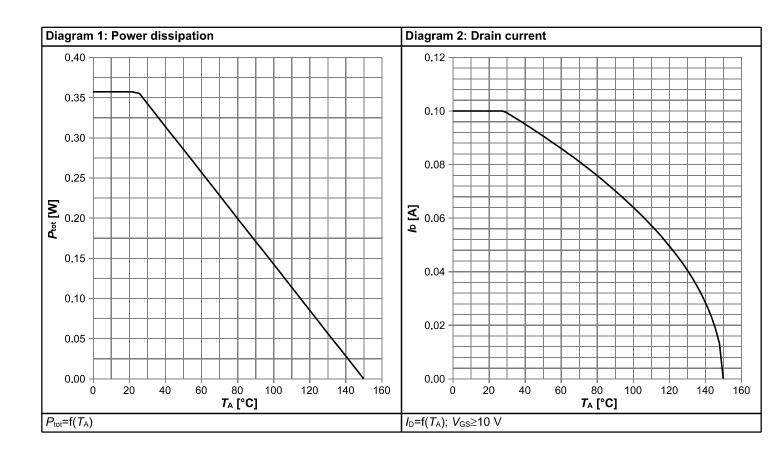
Parameter	Cymphol		Values			Note / Test Condition
	Symbol	Min.	Тур.	Max.	Unit	Note / Test Condition
Gate to source charge	Q _{gs}	-	0.14	-	nC	$V_{\rm DD}$ =200 V, $I_{\rm D}$ =0.04 A, $V_{\rm GS}$ =-3 to 5 V
Gate to drain charge	$Q_{ m gd}$	-	1.3	-	nC	$V_{\rm DD}$ =200 V, $I_{\rm D}$ =0.04 A, $V_{\rm GS}$ =-3 to 5 V
Gate charge total	Qg	-	2.3	-	nC	$V_{\rm DD}$ =200 V, $I_{\rm D}$ =0.04 A, $V_{\rm GS}$ =-3 to 5 V
Gate plateau voltage	V _{plateau}	-	-0.28	-	V	$V_{\rm DD}$ =200 V, $I_{\rm D}$ =0.04 A, $V_{\rm GS}$ =-3 to 5 V

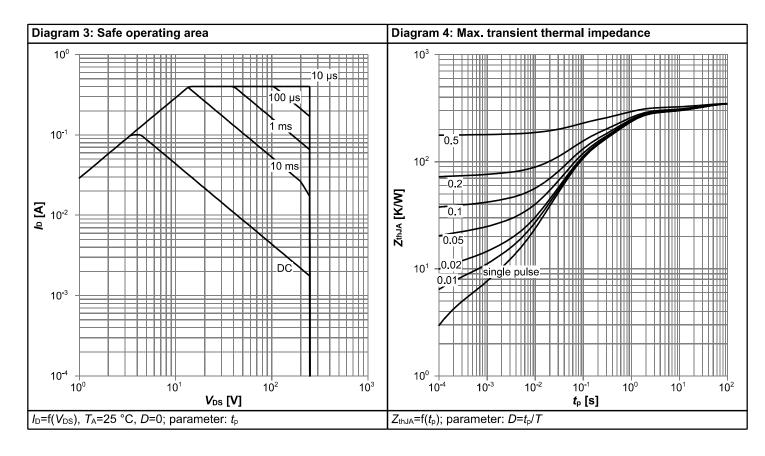
Table 7 Reverse diode

Parameter	Comple of		Values			N 4 4 7 4 0 1111
	Symbol	Min.	Тур.	Max.	Unit	Note / Test Condition
Diode continous forward current	Is	-	-	0.10	Α	T _A =25 °C
Diode pulse current	I _{S,pulse}	-	-	0.4	Α	T _A =25 °C
Diode forward voltage	$V_{ extsf{SD}}$	-	0.81	1.2	V	V _{GS} =-3 V, I _F =0.1 A, T _j =25 °C
Reverse recovery time	t _{rr}	-	8.6	12.9	ns	V _R =50 V, I _F =0.04 A, d <i>i</i> _F /d <i>t</i> =100 A/μs
Reverse recovery charge	Q _{rr}	-	2.1	3.1	nC	V _R =50 V, I _F =0.04 A, di _F /dt=100 A/μs

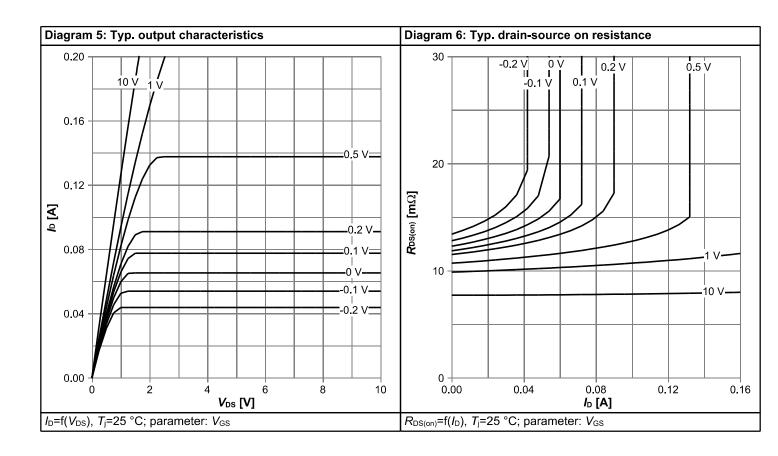


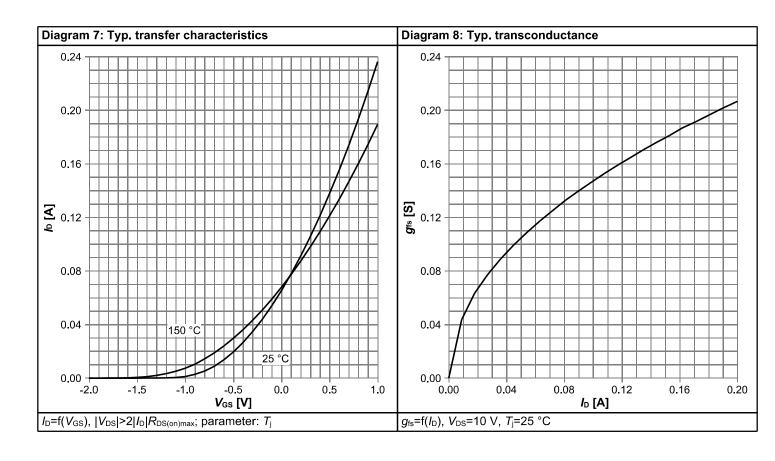
4 Electrical characteristics diagrams



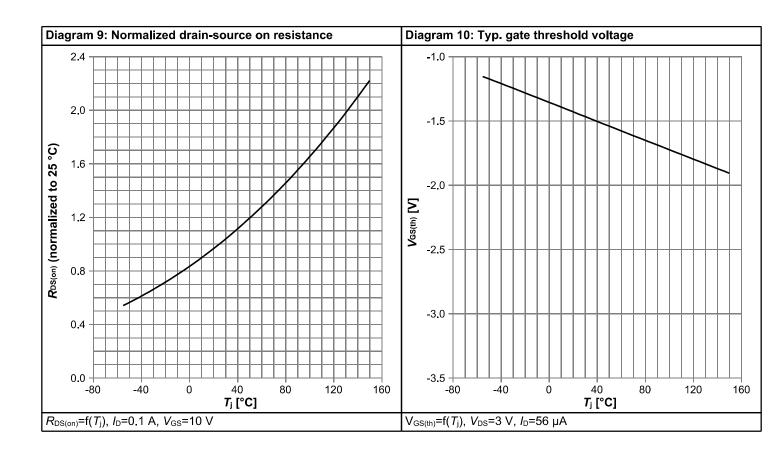


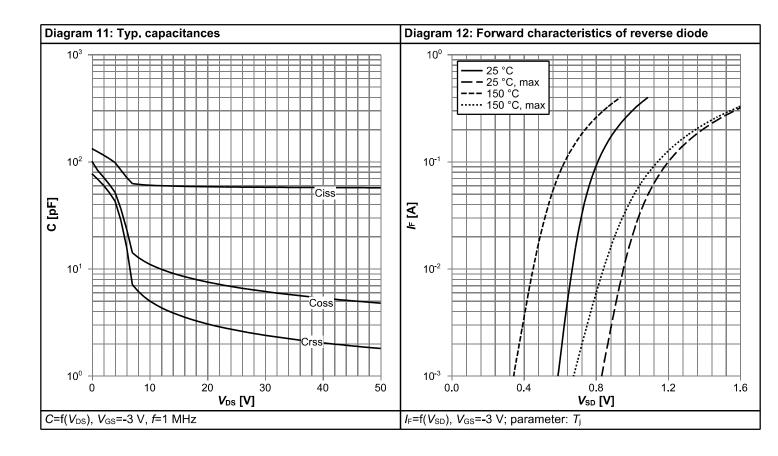




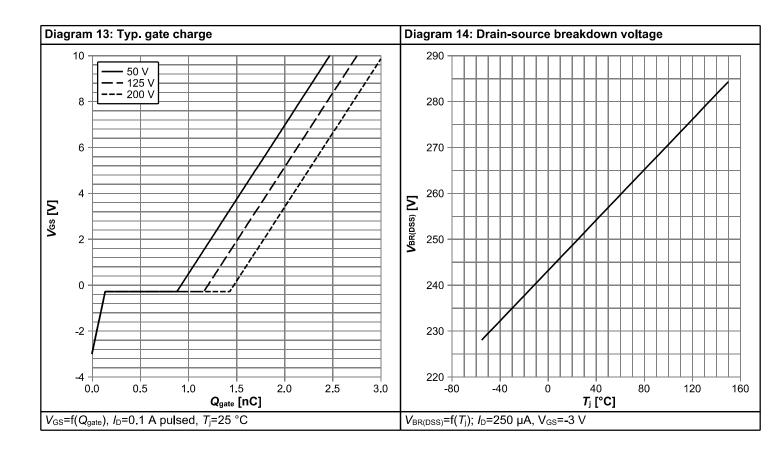


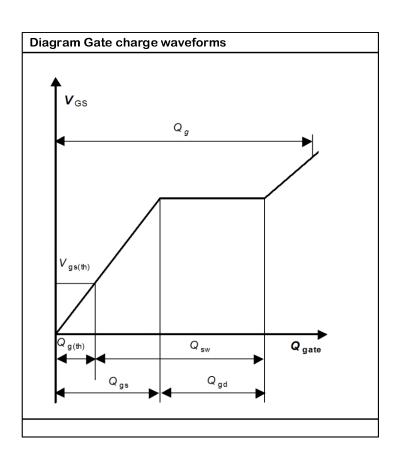






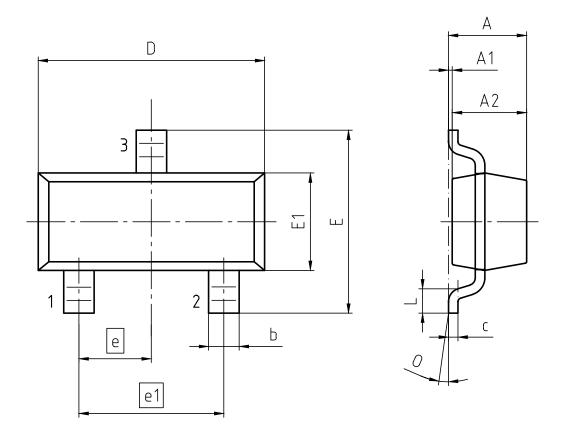








5 Package Outlines



PACKAGE - GROUP NUMBER:	PG-SOT	PG-SOT23-3-U01				
REVISION: 01	DATE: (09.12.2020				
DIMENSIONS	MILLIM	ETERS				
DIMENSIONS	MIN.	MAX.				
Α	0.89	1.12				
A1	0.01	0.10				
A2	0.88	1.02				
b	0.30	0.50				
С	80.0	0.20				
D	2.80	3.04				
E	2.10	2.64				
E1	1.20	1.40				
е	0.	0.95				
e1	1.90					
L	0.15 0.60					
0	0°	8°				

Figure 1 Outline PG-SOT23, dimensions in mm



Revision History

BSS139I

Revision: 2021-03-17, Rev. 2.1

Previous Revision

Trovidus (Consider							
Revision	Revision Date Subjects (major changes since last revision)						
2.0	2021-01-25	Release of final version					
2.1	2021-03-17	Update technology naming					

Trademarks

All referenced product or service names and trademarks are the property of their respective owners.

We Listen to Your Comments

Any information within this document that you feel is wrong, unclear or missing at all? Your feedback will help us to continuously improve the quality of this document. Please send your proposal (including a reference to this document) to: erratum@infineon.com

Published by Infineon Technologies AG 81726 München, Germany © 2020 Infineon Technologies AG All Rights Reserved.

Legal Disclaimer

The information given in this document shall in no event be regarded as a guarantee of conditions or characteristics ("Beschaffenheitsgarantie").

With respect to any examples, hints or any typical values stated herein and/or any information regarding the application of the product, Infineon Technologies hereby disclaims any and all warranties and liabilities of any kind, including without limitation warranties of non-infringement of intellectual property rights of any third party.

In addition, any information given in this document is subject to customer's compliance with its obligations stated in this document and any applicable legal requirements, norms and standards concerning customer's products and any use of the product of Infineon Technologies in customer's applications.

The data contained in this document is exclusively intended for technically trained staff. It is the responsibility of customer's technical departments to evaluate the suitability of the product for the intended application and the completeness of the product information given in this document with respect to such application.

Information

For further information on technology, delivery terms and conditions and prices please contact your nearest Infineon Technologies Office (www.infineon.com).

Warnings

Due to technical requirements, components may contain dangerous substances. For information on the types in question, please contact the nearest Infineon Technologies Office.

The Infineon Technologies component described in this Data Sheet may be used in life-support devices or systems and/or automotive, aviation and aerospace applications or systems only with the express written approval of Infineon Technologies, if a failure of such components can reasonably be expected to cause the failure of that life-support, automotive, aviation and aerospace device or system or to affect the safety or effectiveness of that device or system. Life support devices or systems are intended to be implanted in the human body or to support and/or maintain and sustain and/or protect human life. If they fail, it is reasonable to assume that the health of the user or other persons may be endangered.

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Infineon:

BSS139IXTSA1